LOW POWER / SMALL PACKAGE / 24Bit COLOR LVDS TRANSMITTER

General Description

The THC63LVDM87 transmitter is designed to support pixel data transmission between Host and Flat Panel Display up to 1080p/WUXGA resolutions.

The THC63LVDM87 converts 28bits of CMOS/TTL data into LVDS(Low Voltage Differential Signaling) data stream. The transmitter can be programmed for rising edge or falling edge clocks through a dedicated pin. At a transmit clock frequency of 160MHz, 24bits of RGB data and 4bits of timing and control data (HSYNC, VSYNC, DE, CONT1) are transmitted at an effective rate of 1120Mbps per LVDS channel.

Features

- Low power 1.8V CMOS design
- 5mm x 5mm/49pin/0.65mm pitch VFBGA Package applicable to non-HDI PCB
- Wide dot clock range, 8-160MHz suited for TV Signal: NTSC(12.27MHz) - 1080p(148.5MHz) PC Signal: QVGA(8MHz) - WUXGA(154MHz)
- Supports 1.8V single power supply
- 1.8V/2.5V/3.3V CMOS inputs are supported by setting IOVCC=1.8V/2.5V/3.3V
- LVDS swing is reducible by RS-pin to reduce EMI and power consumption
- PLL requires no external components
- Supports spread spectrum clock generator
- On chip jitter filtering
- Power down mode
- Input clock triggering edge is selectable by R/F-pin

THC63LVDM87 TTL/CMOS LVDS Outputs Inputs PARALLEL TO SERIAL 7 TA0-6 TA +/-7 TB0-6 TB +/-7 TC0-6 TC +/-7 TD0-6 _ TD +/-F (56-1120Mbit/On Each LVDS Channel) TRANSMITTER TCLK +/-CLKIN PLL (8 to 160MHz) CLOCK R/F (LVDS) 8-160MHz /PDWN

RS

Block Diagram

Pin Out

	1	2	3	4	5	6	7	1		
A	TA6	TA5	TA4	ТАЗ	TA2	TA1	TAO	A		
в	TB4	TD3	TD2	TD1	TD0	TA-	TA+	в		
с	TB5	TBO	GND	vcc	RS	TB-	TB+	с		
D	TB6	TB1	GND	IO VCC	LVDS VCC	TC-	TC+	D		
E	тсо	TB2	GND	PLL VCC	R/F	TCLK-	TCLK+	E		
F	TC1	твз	TD4	TD5	TD6	TD-	TD+	F		
G	TC2	тсз	TC4	TC5	TC6	CLKIN	/PDWN	G		
	1	2	3	4	5	6	7			

TOP VIEW



Pin Description

Pin Name	Pin #	Туре	Description				
TA+, TA-	B7, B6	LVDS OUT					
TB+, TB-	C7, C6	LVDS OUT	LVDS Data Out.				
TC+, TC-	D7, D6	LVDS OUT					
TD+, TD-	F7, F6	LVDS OUT	1				
TCLK+, TCLK-	E7, E6	LVDS OUT	LVDS Clock Out.				
TA0 ~ TA6	A7,A6,A5,A4,A3,A2,A1	IN					
TB0 ~ TB6	C2,D2,E2,F2,B1,C1,D1	IN	Pixel Data Inputs.				
TC0 ~ TC6	E1,F1,G1,G2,G3,G4,G5	IN					
TD0 ~ TD6	B5,B4,B3,B2,F3,F4,F5	IN					
/PDWN	G7	IN	 H: Normal operation, L: Power down (All outputs are Hi-Z and all circuits are stand- by mode with minimum current(ITCCS)) 				
RS	C5	IN	LVDS swing mode select. RS LVDS Swing(VOD, see Fig4) H 350mV L 200mV				
R/F	E5	IN	Input Clock Triggering Edge Select. H: Rising edge, L: Falling edge				
CLKIN	G6	IN	Clock input.				
IO VCC	D4	Power	Power Supply Pin for IO Inputs.				
VCC	C4	Power	Power Supply Pin for digital circuitry.				
LVDS VCC	D5	Power	Power Supply Pin for LVDS Outputs.				
PLL VCC	E4	Power	Power Supply Pin for PLL circuitry.				
GND	C3,D3,E3	Ground	Ground Pins for Common.				

Absolute Maximum Ratings

Supply Voltage (IO VCC)	-0.3V ~ +4.0V
Supply Voltage (VCC, PLL VCC, LVDS VCC)	-0.3V ~ +2.1V
CMOS/TTL Input Voltage	-0.3V ~ (IO VCC + 0.3V)
LVDS Transmitter Output Voltage	-0.3V ~ (LVDS VCC + 0.3V)
LVDS Total Output Current	-50mA ~ 50mA
Junction Temperature (Tj)	+125°C
Storage Temperature Range	-55°C ~ +125°C
Reflow Peak Temperature / Time	+260°C / 10sec.
Maximum Power Dissipation @+25°C	1.3W

Recommended Operating Conditions

Parameter			Тур	Max	Units
Sup	1.62	1.8/2.5/3.3	3.6	V	
Supply Voltage (PLLVCC / LVDSVCC / VCC)			1.8	1.98	V
Operating Ambient Temperature (Ta)				85	°C
	Input	8		160	MHz
Clock Frequency	LVDS Output	8		160	MHz

Electrical Characteristics

CMOS/TTL DC Specifications

Over recommended operating supply and temperature ranges unless otherwise spe								
Symbol	Parameter	Conditions	Min.	Тур.	Max.	Units		
V _{IH18}	High Level Input Voltage	IOVCC=1.62~1.98V	0.65 IOVCC		IOVCC+0.3	V		
V _{IL18}	Low Level Input Voltage	10,000=1.02~1.90	-0.3		0.35 IOVCC	V		
V _{IH25}	High Level Input Voltage	IOVCC=2.3~2.7V	1.7		IOVCC+0.3	V		
V _{IL25}	Low Level Input Voltage	10000=2.3~2.70	-0.3		0.7	V		
V _{IH33}	High Level Input Voltage	IOVCC=3.0~3.6V	2.0		IOVCC+0.3	V		
V _{IL33}	Low Level Input Voltage	10,00=3.0~3.00	-0.3		0.8	V		
I _{INC}	Input Current	VIN=GND~IOVCC	-10		10	μΑ		

LVDS Transmitter DC Specifications

	Over	recommended o	perating supply and ten	nperature r	anges unle	ss otherwis	e specifie
Symbol	Parameter	Parameter Conditions		Min.	Тур.	Max.	Units
VOD	Differential Output Voltage	RL=100Ω	Normal swing RS=H	250	350	450	mV
		RL=10022	Reduced swing RS=L	140	200	300	mV
ΔVOD	Change in VOD between complementary output states				35	mV	
VOC	Common Mode Voltage	RL=100Ω		1.125	1.25	1.375	V
∆VOC	Change in VOC between complementary output states					35	mV
I _{OS}	Output Short Circuit Current	V _{OUT} =GND			100	mA	
I _{OZ}	Output TRI-STATE Current	/PDWN=L, V _{OUT} =GND~LVDSVCC		-20		20	μA

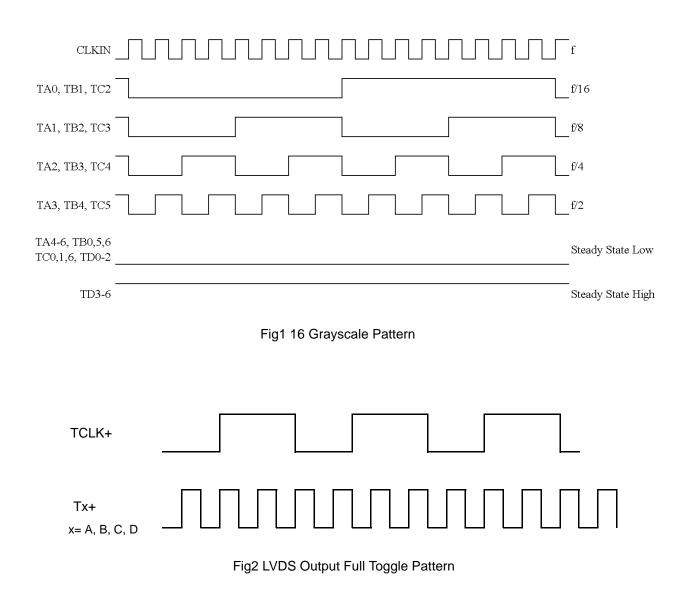
Supply Current

Symbol	Parameter		Condition(*)	Тур.	Max.	Units	
-	Transmitter Supply Current	RL=100Ω CL=5pF	RS=H	f=37MHz	25	33	mA
			Normal swing mode	f=71MHz	30	46	mA
				f=160MHz	44	79	mA
ITCCW			RS=L Reduced swing mode	f=37MHz	19	27	mA
				f=71MHz	24	40	mA
				f=160MHz	38	73	mA
I _{TCCS}	Transmitter Power Down Supply Current	/PDWN = L	., All Inputs = L or I	4	1	50	μA

Over recommended operating supply and temperature ranges unless otherwise specified.

(a) All Typ. values are at Vcc=1.8V, Ta=25 °C. The 16 Grayscale Pattern (Fig1) inputs test for a typical display pattern.

(b) All Max. values are at Vcc=1.98V, Ta=85 °C . LVDS Output Full Toggle Pattern (Fig2) produces maximum switching frequency for all the LVDS outputs.



Switching Characteristics

Over recommended operating supply and temperature ranges unless otherwise specified.

Symbol	Parameter	Min.	Тур.	Max.	Units
t _{TCP}	CLK IN Period	6.25	Т	125	ns
t _{TCH}	CLK IN High Time	0.35T	0.5T	0.65T	ns
t _{TCL}	CLK IN Low Time	0.35T	0.5T	0.65T	ns
t _{TCD}	CLK IN to TCLK+/- Delay (Fig4)	5T+3.1		5T+8	ns
t _{TS}	TTL Data Setup to CLK IN	0.8			ns
t _{TH}	TTL Data Hold from CLK IN	0.8			ns
t _{LVT}	LVDS Transition Time		0.6	1.5	ns
t _{TOP1}	Output Data Position0 (T=6.25ns~15ns)	-0.15	0.0	+0.15	ns
t _{TOP0}	Output Data Position1 (T=6.25ns~15ns)	$\frac{T}{7} - 0.15$	T 7	$\frac{T}{7}$ + 0.15	ns
t _{TOP6}	Output Data Position2 (T=6.25ns~15ns)	$2\frac{T}{7} - 0.15$	$2\frac{T}{7}$	$2\frac{T}{7} + 0.15$	ns
t _{TOP5}	Output Data Position3 (T=6.25ns~15ns)	$3\frac{T}{7} - 0.15$	3 7 7	$3\frac{T}{7} + 0.15$	ns
t _{TOP4}	Output Data Position4 (T=6.25ns~15ns)	$4\frac{T}{7} - 0.15$	$4\frac{T}{7}$	$4\frac{T}{7} + 0.15$	ns
t _{TOP3}	Output Data Position5 (T=6.25ns~15ns)	$5\frac{T}{7} - 0.15$	$5\frac{T}{7}$	$5\frac{T}{7} + 0.15$	ns
t _{TOP2}	Output Data Position6 (T=6.25ns~15ns)	$6\frac{T}{7} - 0.15$	$6\frac{T}{7}$	$6\frac{T}{7} + 0.15$	ns
t _{TPLL}	Phase Lock Loop Set			10.0	ms

AC Timing Diagrams

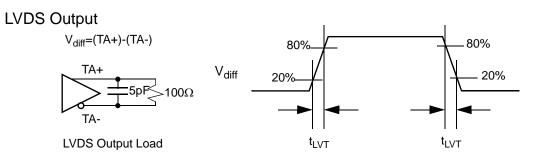


Fig3. LVDS Output Load and Transition Time

AC Timing Diagrams

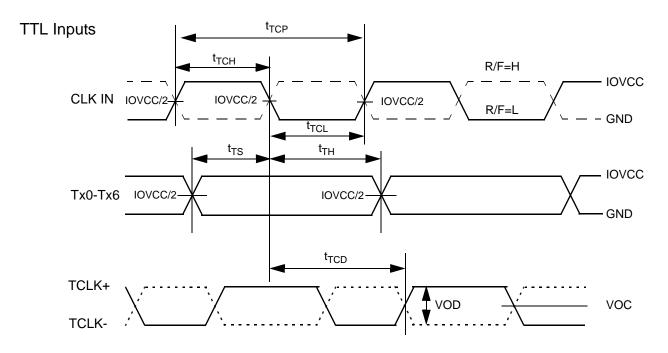
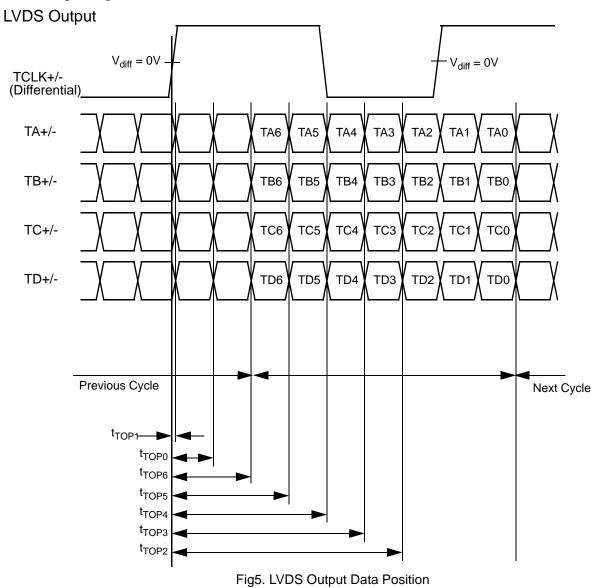


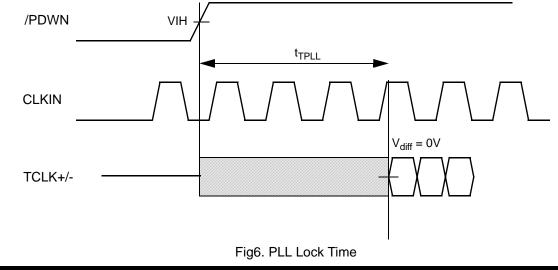
Fig4. CLKIN Period, High/Low Time, Setup/Hold Timing

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AC Timing Diagrams



Phase Lock Loop Set Time



Note

1)Cable Connection and Disconnection

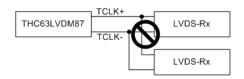
Don't connect and disconnect the LVDS cable, when the power is supplied to the system.

2)GND Connection

Connect the each GND of the PCB which THC63LVDM87 and LVDS-Rx on it. It is better for EMI reduction to place GND cable as close to LVDS cable as possible.

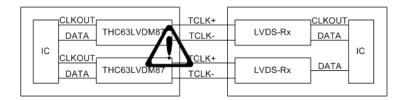
3)Multi Drop Connection

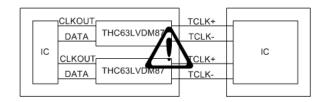
Multi drop connection is not recommended.



4)Asynchronous use

Asynchronous use such as following systems are not recommended.

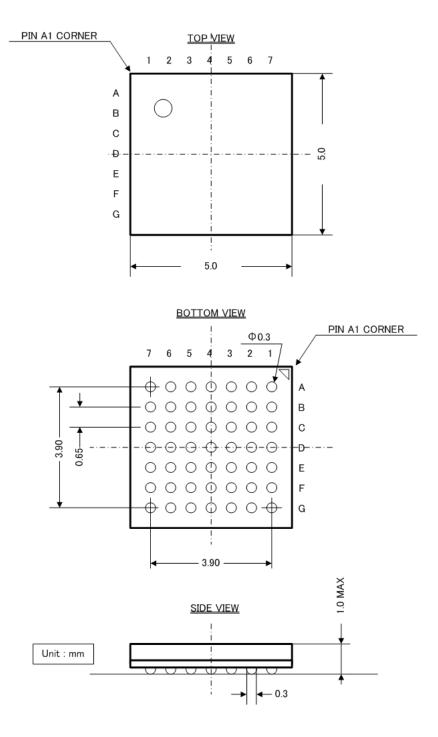




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Package

VFBGA



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